74AUP1G132

Low-power 2-input NAND Schmitt trigger

Rev. 10 — 23 September 2024

Product data sheet

1. General description

The 74AUP1G132 is a single 2-input NAND gate with Schmitt-trigger inputs. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- · Overvoltage tolerant inputs to 3.6 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator.



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4. Ordering information

Table 1. Ordering information

| Type number | Package | | | |
|--------------|-------------------|--------|--|----------------|
| | Temperature range | Name | Description | Version |
| 74AUP1G132GW | -40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm | SOT353-1 |
| 74AUP1G132GM | -40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm | SOT886 |
| 74AUP1G132GN | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm | <u>SOT1115</u> |
| 74AUP1G132GS | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm | SOT1202 |
| 74AUP1G132GX | -40 °C to +125 °C | X2SON5 | plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm | SOT1226-3 |
| 74AUP1G132GZ | -40 °C to +125 °C | XSON5 | plastic thermal enhanced extremely thin small outline package with side-wettable flanks (SWF); no leads; 5 terminals; body 1.1 × 0.85 × 0.5 mm | SOT8065-1 |

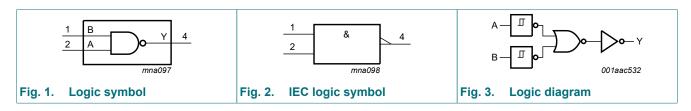
5. Marking

Table 2. Marking

| and all marking | | | | | | | |
|-----------------|------------------|--|--|--|--|--|--|
| Type number | Marking code [1] | | | | | | |
| 74AUP1G132GW | аЕ | | | | | | |
| 74AUP1G132GM | аЕ | | | | | | |
| 74AUP1G132GN | аЕ | | | | | | |
| 74AUP1G132GS | аЕ | | | | | | |
| 74AUP1G132GX | аЕ | | | | | | |
| 74AUP1G132GZ | аЕ | | | | | | |
| | | | | | | | |

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

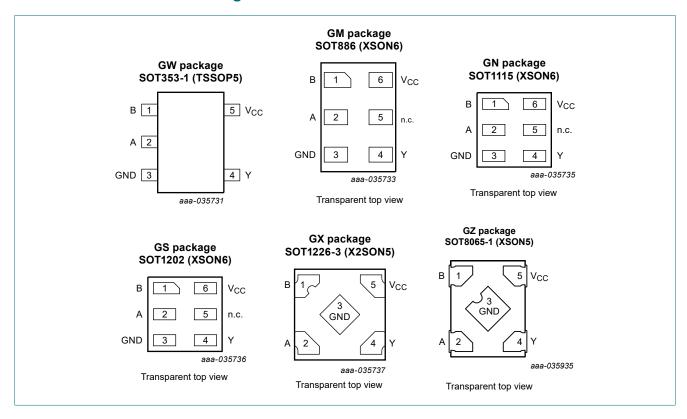
6. Functional diagram



Low-power 2-input NAND Schmitt trigger

7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

| Symbol | Pin | Description | |
|-----------------|--------------------------|-------------|----------------|
| | TSSOP5, XSON5 and X2SON5 | | |
| В | 1 | 1 | data input |
| A | 2 | 2 | data input |
| GND | 3 | 3 | ground (0 V) |
| Υ | 4 | 4 | data output |
| n.c. | - | 5 | not connected |
| V _{CC} | 5 | 6 | supply voltage |

Low-power 2-input NAND Schmitt trigger

8. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

| Input | Output | |
|-------|--------|---|
| A | В | Υ |
| L | L | Н |
| L | Н | Н |
| Н | L | Н |
| Н | Н | L |

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--|------|------|------|
| V _{CC} | supply voltage | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V _I < 0 V | -50 | - | mA |
| VI | input voltage | [1 | -0.5 | +4.6 | V |
| I _{OK} | output clamping current | V _O < 0 V | -50 | - | mA |
| Vo | output voltage | Active mode and Power-down mode [1 | -0.5 | +4.6 | V |
| Io | output current | V _O = 0 V to V _{CC} | - | ±20 | mA |
| I _{CC} | supply current | | - | 50 | mA |
| I _{GND} | ground current | | -50 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2] | - | 250 | mW |

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------|--|-----|-----------------|------|
| V_{CC} | supply voltage | | 0.8 | 3.6 | V |
| VI | input voltage | | 0 | 3.6 | V |
| V _O | output voltage | Active mode | 0 | V _{CC} | V |
| | | Power-down mode; V _{CC} = 0 V | 0 | 3.6 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |

^[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: Ptot derates linearly with 3.0 mW/K above 67 °C.

For SOT8065-1 (XSON5) package: P_{tot} derates linearly with 3.2 mW/K above 72 °C.

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11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|--|------------------------|-----|-----------------------|------|
| T _{amb} = 2 | 5°C | | | | | • |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.75 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.11 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.32 | - | - | V |
| | | I_{O} = -2.3 mA; V_{CC} = 2.3 V | 2.05 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.9 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.72 | - | - | V |
| | | I_{O} = -4.0 mA; V_{CC} = 3.0 V | 2.6 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.31 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.31 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.31 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.44 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.31 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.44 | V |
| l _l | input leakage current | V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V | - | - | ±0.1 | μA |
| I _{OFF} | power-off leakage current | V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$ | - | - | ±0.2 | μΑ |
| Δl _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.2 | μA |
| I _{CC} | supply current | V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.5 | μA |
| Δl _{CC} | additional supply current | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1] | - | - | 40 | μA |
| C _I | input capacitance | $V_I = GND \text{ or } V_{CC}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$ | - | 1.1 | - | pF |
| Co | output capacitance | $V_O = GND; V_{CC} = 0 V$ | - | 1.7 | - | pF |
| T _{amb} = - | 40 °C to +85 °C | 1 | | | | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | T |
| | | I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.7 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.03 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.30 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.97 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.85 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.67 | - | - | V |
| | | $I_{\rm O}$ = -4.0 mA; $V_{\rm CC}$ = 3.0 V | 2.55 | - | - | V |

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|--|------------------------|-----|------------------------|------|
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.37 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.35 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.33 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.45 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | _ | 0.33 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.45 | V |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.5 | μA |
| I _{OFF} | power-off leakage current | V_1 or $V_0 = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$ | - | - | ±0.5 | μA |
| ΔI _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.6 | μA |
| I _{CC} | supply current | V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.9 | μΑ |
| ΔI _{CC} | additional supply current | $V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1] | - | - | 50 | μA |
| T _{amb} = -4 | 40 °C to +125 °C | | | 1 | | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V | V _{CC} - 0.11 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.6 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 0.93 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.17 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.77 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.67 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.40 | - | - | V |
| | | I_{O} = -4.0 mA; V_{CC} = 3.0 V | 2.30 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.11 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.33 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.41 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.39 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.36 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.50 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.36 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.50 | V |
| I _I | input leakage current | V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V | - | - | ±0.75 | μA |
| I _{OFF} | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.75 | μA |
| Δl _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.75 | μA |
| I _{CC} | supply current | V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 1.4 | μA |
| Δl _{CC} | additional supply current | $V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1] | - | _ | 75 | μA |

^[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

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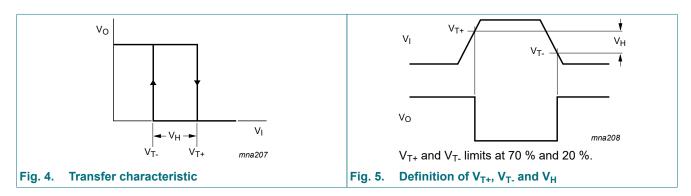
11.1. Transfer characteristics

Table 8. Transfer characteristics

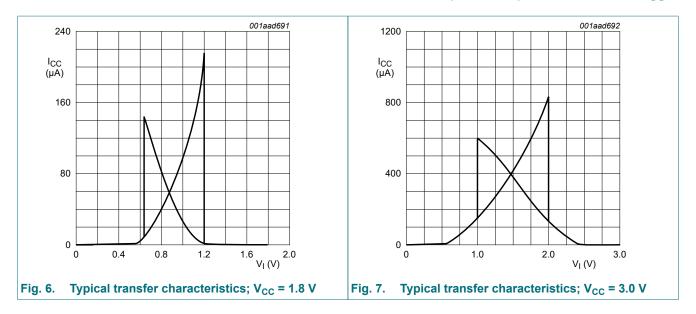
Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 9.

| Symbol | Parameter | Conditions | | 25 °C | | | °C to 5 °C | | °C to 5 °C | Unit |
|-----------------|-----------------------|--|------|-------|------|------|---------------|------|---------------|------|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| V _{T+} | positive-going | see Fig. 4 and Fig. 5 | | | | | | | | |
| | threshold voltage | V _{CC} = 0.8 V | 0.30 | - | 0.60 | 0.30 | 0.60 | 0.30 | 0.62 | V |
| | Voltage | V _{CC} = 1.1 V | 0.53 | - | 0.90 | 0.53 | 0.90 | 0.53 | 0.92 | V |
| | | V _{CC} = 1.4 V | 0.74 | - | 1.11 | 0.74 | 1.11 | 0.74 | 1.13 | V |
| | | V _{CC} = 1.65 V | 0.91 | - | 1.29 | 0.91 | 1.29 | 0.91 | 1.31 | V |
| | | V _{CC} = 2.3 V | 1.37 | - | 1.77 | 1.37 | 1.77 | 1.37 | 1.80 | V |
| | | V _{CC} = 3.0 V | 1.88 | - | 2.29 | 1.88 | 2.29 | 1.88 | 2.32 | V |
| V _{T-} | negative-going | see Fig. 4 and Fig. 5 | | | | | | | | |
| | threshold voltage | V _{CC} = 0.8 V | 0.10 | - | 0.60 | 0.10 | 0.60 | 0.10 | 0.60 | V |
| | Voltage | V _{CC} = 1.1 V | 0.26 | - | 0.65 | 0.26 | 0.65 | 0.26 | 0.65 | V |
| | | V _{CC} = 1.4 V | 0.39 | - | 0.75 | 0.39 | 0.75 | 0.39 | 0.75 | V |
| | | V _{CC} = 1.65 V | 0.47 | - | 0.84 | 0.47 | 0.84 | 0.47 | 0.84 | V |
| | | V _{CC} = 2.3 V | 0.69 | - | 1.04 | 0.69 | 1.04 | 0.69 | 1.04 | V |
| | | V _{CC} = 3.0 V | 0.88 | - | 1.24 | 0.88 | 1.24 | 0.88 | 1.24 | V |
| V _H | hysteresis voltage | (V _{T+} - V _{T-}); see <u>Fig. 4</u> , <u>Fig. 5</u> , <u>Fig. 6</u> and <u>Fig. 7</u> | | | | | | | | |
| | | V _{CC} = 0.8 V | 0.07 | - | 0.50 | 0.07 | 0.50 | 0.07 | 0.50 | V |
| | | V _{CC} = 1.1 V | 0.08 | - | 0.46 | 0.08 | 0.46 | 0.08 | 0.46 | V |
| | | V _{CC} = 1.4 V | 0.18 | - | 0.56 | 0.18 | 0.56 | 0.18 | 0.56 | V |
| | | V _{CC} = 1.65 V | 0.27 | - | 0.66 | 0.27 | 0.66 | 0.27 | 0.66 | V |
| | | V _{CC} = 2.3 V | 0.53 | - | 0.92 | 0.53 | 0.92 | 0.53 | 0.92 | V |
| | | V _{CC} = 3.0 V | 0.79 | - | 1.31 | 0.79 | 1.31 | 0.79 | 1.31 | V |

11.2. Waveforms transfer characteristics



Low-power 2-input NAND Schmitt trigger



12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 9.

| Symbol | Parameter | Conditions | | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|----------------------|-------------|------------------------------------|-----|---------|------|------------------|------|-------------------|------|------|
| | | | Min | Typ [1] | Max | Min | Max | Min | Max | |
| C _L = 5 p | F | | | | | | | | | |
| t _{pd} | propagation | A or B to Y; see Fig. 8 [2] | | | | | | | | |
| | delay | V _{CC} = 0.8 V | - | 22.5 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.6 | 6.3 | 13.4 | 2.4 | 15.1 | 2.4 | 16.6 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.2 | 4.6 | 8.2 | 1.9 | 9.7 | 1.9 | 10.7 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 1.9 | 3.9 | 6.6 | 1.7 | 7.9 | 1.7 | 8.7 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | 3.2 | 5.3 | 1.5 | 6.2 | 1.5 | 6.8 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.6 | 2.9 | 4.7 | 1.4 | 5.6 | 1.4 | 6.2 | ns |
| C _L = 10 | pF | | | • | | | | | | |
| F | propagation | A or B to Y; see Fig. 8 [2] | | | | | | | | |
| | delay | V _{CC} = 0.8 V | - | 26.1 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 3.0 | 7.2 | 15.4 | 2.7 | 17.3 | 2.7 | 19.0 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.5 | 5.2 | 9.3 | 2.2 | 11.0 | 2.2 | 12.1 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 2.3 | 4.5 | 7.5 | 2.0 | 9.0 | 2.0 | 9.9 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 2.1 | 3.8 | 6.1 | 1.8 | 7.2 | 1.8 | 7.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | 3.5 | 5.5 | 1.8 | 6.5 | 1.8 | 7.2 | ns |
| C _L = 15 | pF | | | | | ' | | | | |
| t _{pd} | propagation | A or B to Y; see Fig. 8 [2] | | | | | | | | |
| | delay | V _{CC} = 0.8 V | - | 29.6 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 3.3 | 8.0 | 17.2 | 3.0 | 19.4 | 3.0 | 21.3 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.8 | 5.8 | 10.4 | 2.5 | 12.3 | 2.5 | 13.5 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 2.6 | 5.0 | 8.3 | 2.3 | 10.0 | 2.3 | 11.0 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 2.3 | 4.2 | 6.7 | 2.1 | 7.9 | 2.1 | 8.7 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.2 | 3.9 | 6.1 | 2.0 | 7.3 | 2.0 | 8.0 | ns |

Low-power 2-input NAND Schmitt trigger

| Symbol | Parameter | Conditions | | 25 °C | | -40 °C to | o +85 °C | -40 °C to | -40 °C to +125 °C | |
|-----------------------|----------------------|--|-----|---------|------|-----------|----------|-----------|-------------------|----|
| | | | Min | Typ [1] | Max | Min | Max | Min | Max | |
| C _L = 30 | pF | | | | | ' | | | <u>'</u> | |
| t _{pd} | propagation | A or B to Y; see Fig. 8 [2] | | | | | | | | |
| | delay | V _{CC} = 0.8 V | - | 39.9 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 4.3 | 10.2 | 22.6 | 3.8 | 25.4 | 3.8 | 27.9 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 3.6 | 7.3 | 13.3 | 3.2 | 15.8 | 3.2 | 17.4 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 3.2 | 6.3 | 10.6 | 2.9 | 12.8 | 2.9 | 14.1 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 3.0 | 5.3 | 8.5 | 2.7 | 10.1 | 2.7 | 11.1 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.8 | 5.0 | 7.8 | 2.7 | 9.2 | 2.7 | 10.1 | ns |
| C _L = 5 pl | F, 10 pF, 15 pF | and 30 pF | | | | ' | | | ' | |
| C _{PD} | power dissipation | $f_i = 1 \text{ MHz};$ [3] $V_I = \text{GND to } V_{CC}$ | | | | | | | | |
| | capacitance | V _{CC} = 0.8 V | - | 2.6 | - | - | - | - | - | pF |
| | | V _{CC} = 1.1 V to 1.3 V | - | 2.9 | - | - | - | - | - | pF |
| | | V _{CC} = 1.4 V to 1.6 V | - | 3.0 | - | - | - | - | - | pF |
| | | V _{CC} = 1.65 V to 1.95 V | - | 3.2 | - | - | - | - | - | pF |
| | | V _{CC} = 2.3 V to 2.7 V | - | 3.8 | - | - | - | - | - | pF |
| | | V _{CC} = 3.0 V to 3.6 V | - | 4.4 | - | - | - | - | - | pF |

- All typical values are measured at nominal V_{CC}.
- t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1. Waveforms and test circuit

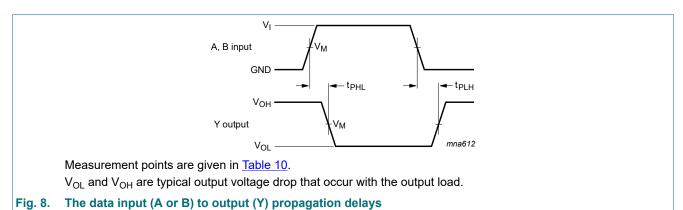
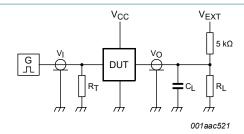


Table 10. Measurement points

| Supply voltage | Output | Input | | | | | |
|-----------------|-----------------------|-----------------------|-----------------|-------------|--|--|--|
| V _{CC} | V _M | V _M | VI | $t_r = t_f$ | | | |
| 0.8 V to 3.6 V | 0.5 × V _{CC} | 0.5 × V _{CC} | V _{CC} | ≤ 3.0 ns | | | |

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Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

 V_{EXT} = External voltage for measuring switching times.

Fig. 9. Test circuit for measuring switching times

Table 11. Test data

| Supply voltage | Load | | V _{EXT} | | |
|-----------------|------------------------------|--------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| V _{CC} | CL | R _L [1] | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open | GND | 2 × V _{CC} |

[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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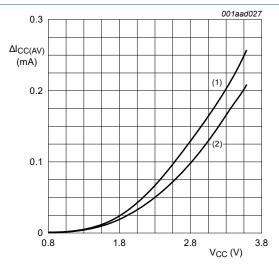
13. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- ΔI_{CC(AV)} = average additional supply current (μA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig. 10.



- (1) Positive-going edge.
- (2) Negative-going edge.

Linear change of V_I between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

Fig. 10. Average I_{CC} as a function of V_{CC}

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14. Package outline

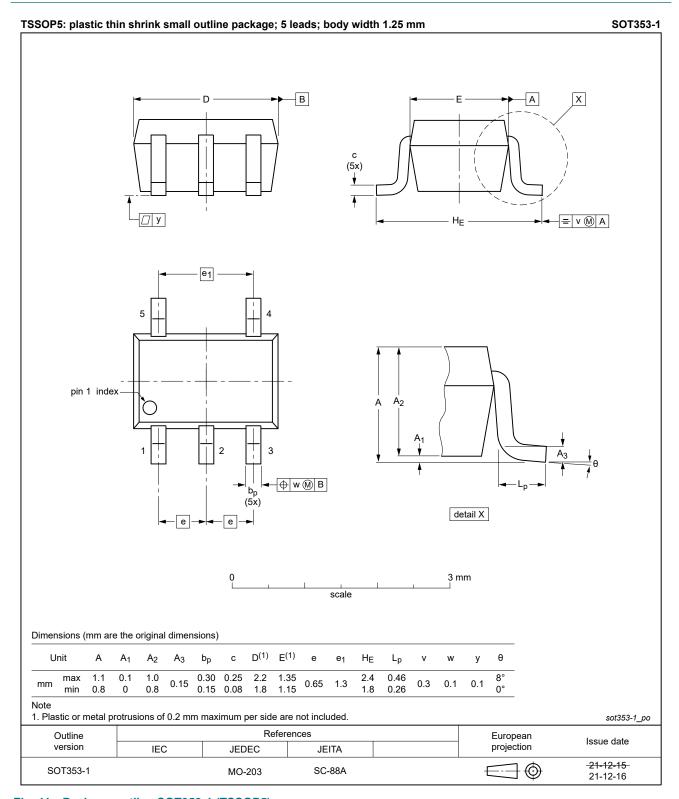


Fig. 11. Package outline SOT353-1 (TSSOP5)

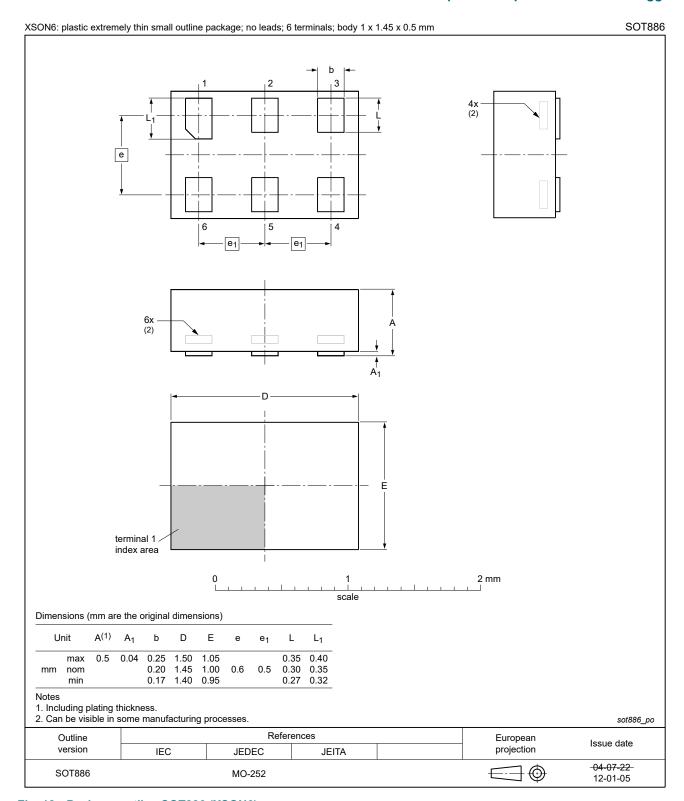


Fig. 12. Package outline SOT886 (XSON6)

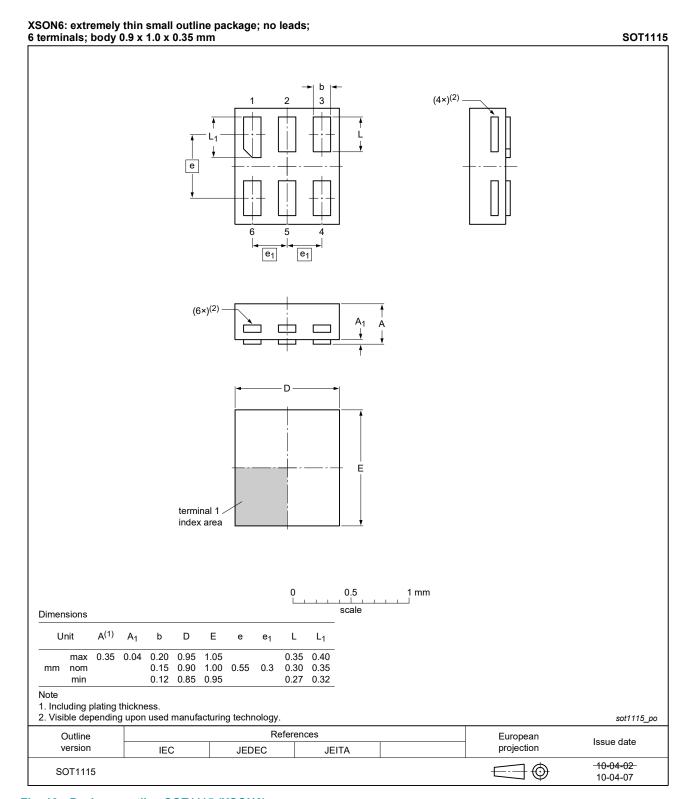


Fig. 13. Package outline SOT1115 (XSON6)

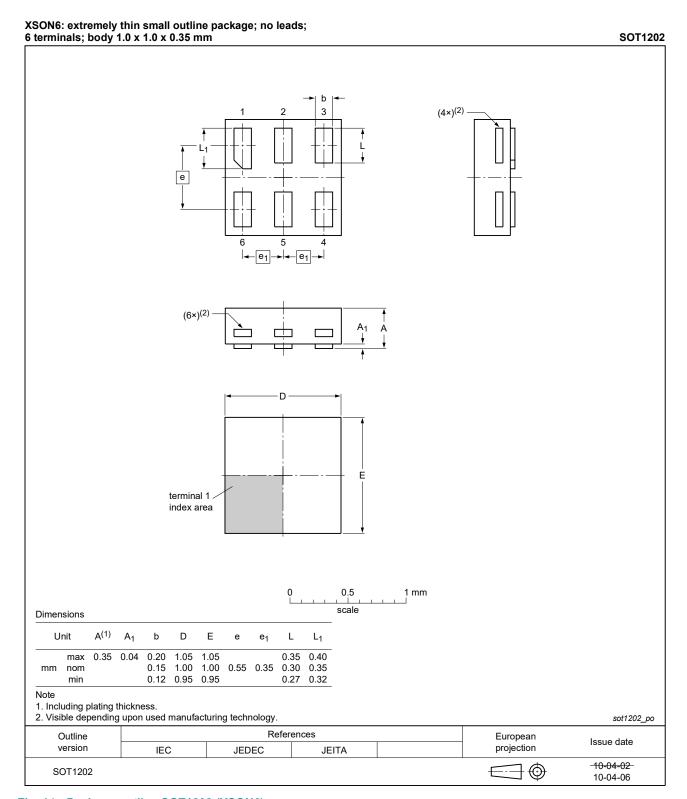


Fig. 14. Package outline SOT1202 (XSON6)

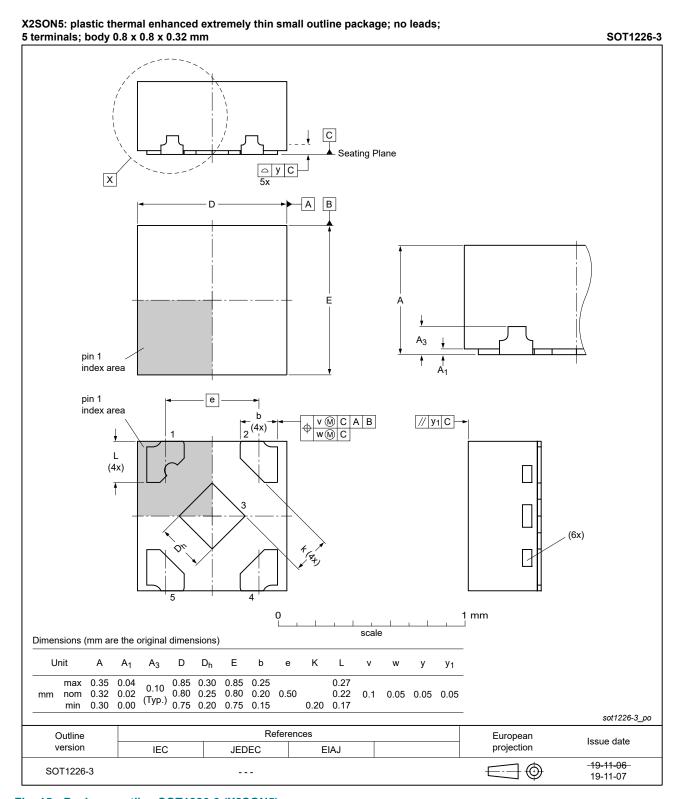


Fig. 15. Package outline SOT1226-3 (X2SON5)

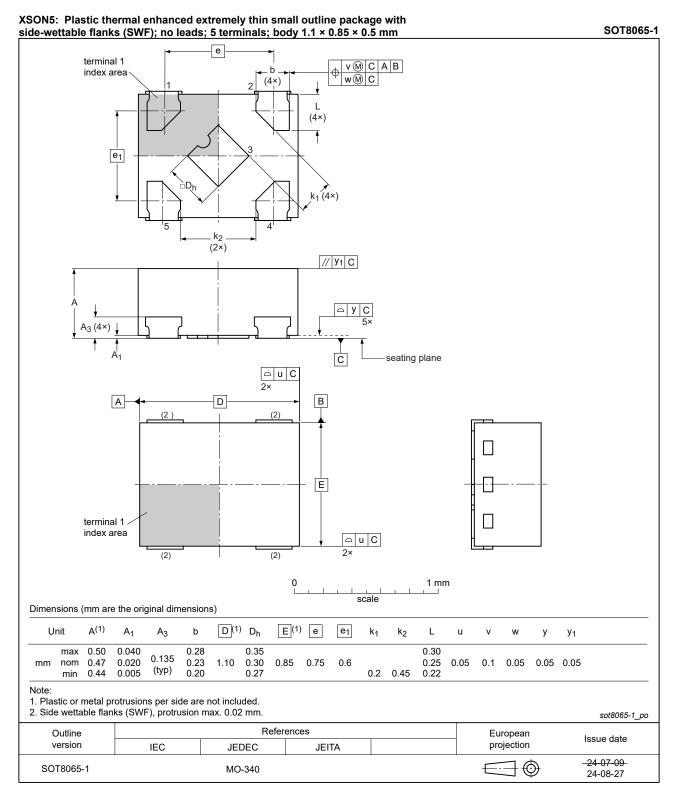


Fig. 16. Package outline SOT8065-1 (XSON5)

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15. Abbreviations

Table 12. Abbreviations

| Acronym | Description | |
|---------|---|--|
| ANSI | American National Standards Institute | |
| CDM | Charged Device Model | |
| DUT | Device Under Test | |
| ESD | ElectroStatic Discharge | |
| ESDA | ElectroStatic Discharge Association | |
| НВМ | Human Body Model | |
| JEDEC | Joint Electron Device Engineering Council | |

16. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
|------------------|--|--|---------------|------------------|--|
| 74AUP1G132 v.10 | 20240923 | Product data sheet | - | 74AUP1G132 v.9.1 | |
| Modifications: | Type number | Type number 74AUP1G132GZ (SOT8065-1/XSON5) added. | | | |
| 74AUP1G132 v.9.1 | 20230711 | 0230711 Product data sheet - 74AUP1G132 v.8 | | | |
| Modifications: | Section 2: E | <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard. | | | |
| 74AUP1G132 v.8 | 20220114 | Product data sheet - 74AUP1G132 v.7 | | | |
| Modifications: | • <u>Fig. 11</u> : Pac | Fig. 11: Package outline drawing for SOT353-1 (TSSOP5) has changed. | | | |
| 74AUP1G132 v.7 | 20210709 | Product data sheet | - | 74AUP1G132 v.6 | |
| Modifications: | Type numberSection 1 ar | SOT1226 (X2SON5) package changed to SOT1226-3 (X2SON5) package. Type number 74AUP1G132GF (SOT891) removed. Section 1 and Section 2 updated. Table 5: Derating values for P_{tot} total power dissipation updated. | | | |
| 74AUP1G132 v.6 | 20190501 | Product data sheet | - | 74AUP1G132 v.5 | |
| Modifications: | of Nexperia. • Legal texts I | The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Pin configuration drawing SOT1226 (X2SON5) updated. | | | |
| 74AUP1G132 v.5 | 20120629 | Product data sheet | - | 74AUP1G132 v.4 | |
| Modifications: | 7. | Added type number 74AUP1G132GX (SOT1226) Package outline drawing of SOT886 (Fig. 12) modified. | | | |
| 74AUP1G132 v.4 | 20111124 | Product data sheet | - | 74AUP1G132 v.3 | |
| Modifications: | Legal pages | Legal pages updated. | | | |
| 74AUP1G132 v.3 | 20101029 | Product data sheet | - | 74AUP1G132 v.2 | |
| 74AUP1G132 v.2 | 20090615 | Product data sheet | - | 74AUP1G132 v.1 | |
| 74AUP1G132 v.1 | 20061020 | Product data sheet | - | - | |

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17. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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